BU508AX

GENERAL DESCRIPTION

High voltage, high-speed switching npn transistors in a fully isolated SOT399 envelope, primarily for use in horizontal deflection circuits of colour television receivers.

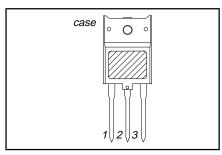
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V _{CESM}	Collector-emitter voltage peak value	$V_{BE} = 0 \text{ V}$	-	1500	V
V _{CEO}	Collector-emitter voltage (open base)		-	700	V
I _C	Collector current (DC)		-	8	Α
1 1	Collector current peak value		-	15	Α
P _{tot}	Total power dissipation	T _{hs} ≤ 25 °C	-	45	W
V _{CEsat}	Collector-emitter saturation voltage	$I_{\rm C} = 4.5 \text{A}; I_{\rm B} = 1.6 \text{A}$	-	1.0	V
Csat	Collector saturation current	f = 16 kHz	4.5	-	Α
t _f	Fall time	$I_{Csat} = 4.5 \text{ A}; f = 16 \text{kHz}$	0.7	-	μs

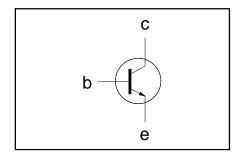
PINNING - SOT399

PIN	DESCRIPTION	
1	base	
2	collector	
3	emitter	
case	isolated	

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum Rating System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CESM}	Collector-emitter voltage peak value	$V_{BE} = 0 \text{ V}$	-	1500	V
V_{CEO}	Collector-emitter voltage (open base)		-	700	l V
I _C	Collector current (DC)		-	8	Α
I _{CM}	Collector current peak value		-	15	Α
l _B	Base current (DC)		-	4	Α
I _{BM}	Base current peak value		-	6	Α
P _{tot}	Total power dissipation	$T_{hs} \leq 25 ^{\circ}C$	-	45	W
T _{stq}	Storage temperature	110	-65	150	°C
$T_{j}^{s,g}$	Junction temperature		-	150	°C

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
R _{th j-hs}	Junction to heatsink	without heatsink compound	-	3.7	K/W
R _{th j-hs}	Junction to heatsink	with heatsink compound	-	2.8	K/W
R _{th j-a}	Junction to ambient	in free air	35	-	K/W

BU508AX

ISOLATION LIMITING VALUE & CHARACTERISTIC

 T_{hs} = 25 $^{\circ}$ C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	Repetitive peak voltage from all three terminals to external heatsink	R.H. ≤ 65 % ; clean and dustfree	1		2500	V
C _{isol}	Capacitance from T2 to external heatsink	f = 1 MHz	1	22	-	pF

STATIC CHARACTERISTICS

 T_{hs} = 25 $^{\circ}$ C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CES}	Collector cut-off current 1	$egin{aligned} V_{BE} &= 0 \ V; \ V_{CE} &= V_{CESMmax} \ V_{BE} &= 0 \ V; \ V_{CE} &= V_{CESMmax}; \end{aligned}$	-	-	1.0	mA
I _{CES}		$V_{BE} = 0 \text{ V}; V_{CE} = V_{CESMmax};$	-	-	2.0	mA
I _{EBO}	Emitter cut-off current	$ T_j = 125 ^{\circ}C$ $ V_{EB} = 6.0 ^{\circ}V; I_C = 0 ^{\circ}A$	_	_	10	mA
V _{CEOsus}	Collector-emitter sustaining voltage	$I_{B} = 0 \text{ A}; I_{C} = 100 \text{ mA};$	700	-	-	V
 		L = 25 mH			, ,	
V _{CEsat}	Collector-emitter saturation voltages	$I_{\rm C} = 4.5 \text{ A}; I_{\rm B} = 1.6 \text{ A}$	-	-	1.0	l V
V _{BEsat}	Base-emitter saturation voltage DC current gain	$I_{C}^{c} = 4.5 \text{ A}; I_{B}^{c} = 2 \text{ A}$ $I_{C} = 100 \text{ mA}; V_{CE} = 5 \text{ V}$	6	13	1.1 30	V -
n _{FE}	DC current gain	$I_C = 100 \text{ mA}, V_{CE} = 5 \text{ V}$	U	13	30	-

DYNAMIC CHARACTERISTICS

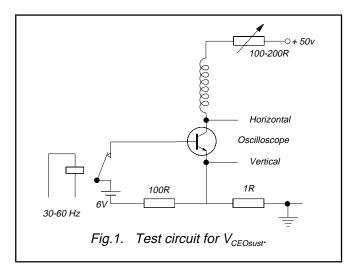
 T_{hs} = 25 $^{\circ}$ C unless otherwise specified

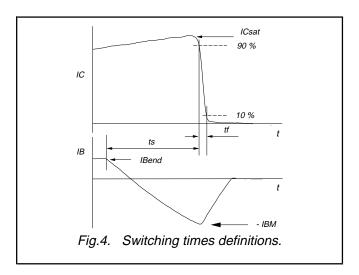
SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
f_T	Transition frequency at f = 5 MHz	$I_{\rm C} = 0.1 \text{ A; V}_{\rm CE} = 5 \text{ V}$	7	1	MHz
C _c	Collector capacitance at f = 1MHz	V _{CB} = 10 V	125	-	pF
t _s	Switching times (16 kHz line deflection circuit) Turn-off storage time	$ \begin{vmatrix} I_{Csat} = 4.5 \text{ A;} L_c \text{ 1 mH;} C_{fb} = 4 \text{ nF} \\ I_{B(end)} = 1.4 \text{ A;} L_B = 6 \mu\text{H;} \text{ -V}_{BB} = \text{-4 V;} \\ -I_{BM} = 2.25 \text{ A} \end{vmatrix} $	6.5	-	μs
tf	Turn-off fall time		0.7	-	μs

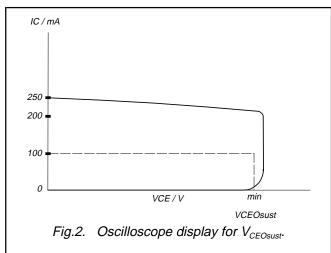
September 1997 2 Rev 1.100

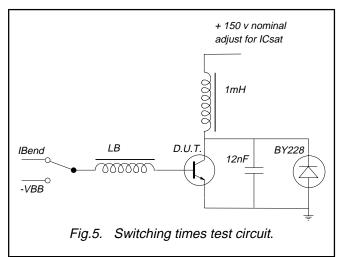
¹ Measured with half sine-wave voltage (curve tracer).

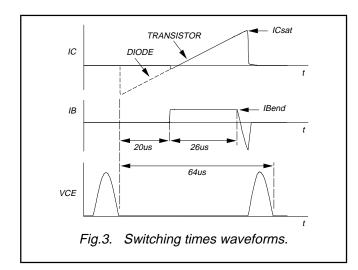
BU508AX

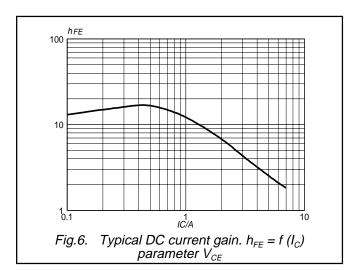












BU508AX

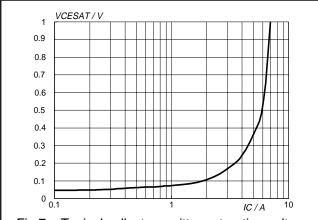


Fig.7. Typical collector-emitter saturation voltage. V_{CE} sat = $f(I_C)$; parameter I_C/I_B

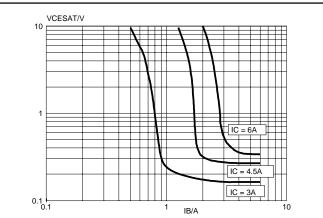


Fig.9. Typical collector-emitter saturation voltage. V_{CE} sat = $f(I_B)$; parameter I_C

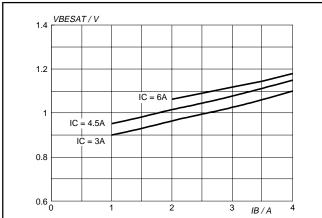


Fig.8. Typical base-emitter saturation voltage. V_{BE} sat = $f(I_B)$; parameter I_C

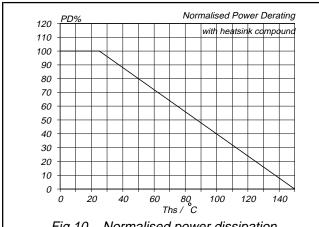


Fig.10. Normalised power dissipation. $PD\% = 100 \cdot P_D/P_{D.25^{\circ}C} = f(T_{hs})$

BU508AX

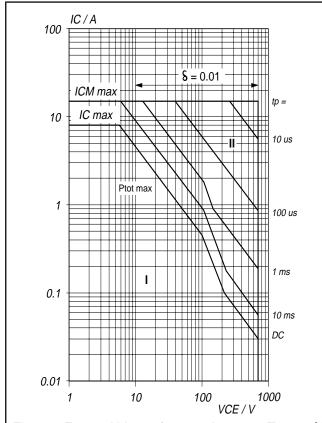


Fig.11. Forward bias safe operating area. $T_{hs} = 25^{\circ}C$ I Region of permissible DC operation. II Extension for repetitive pulse operation.

NB: Mounted with heatsink compound and 30 ± 5 newton force on the centre of the envelope.

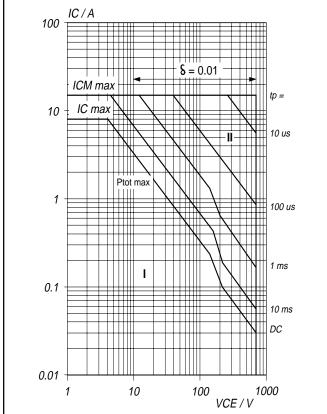
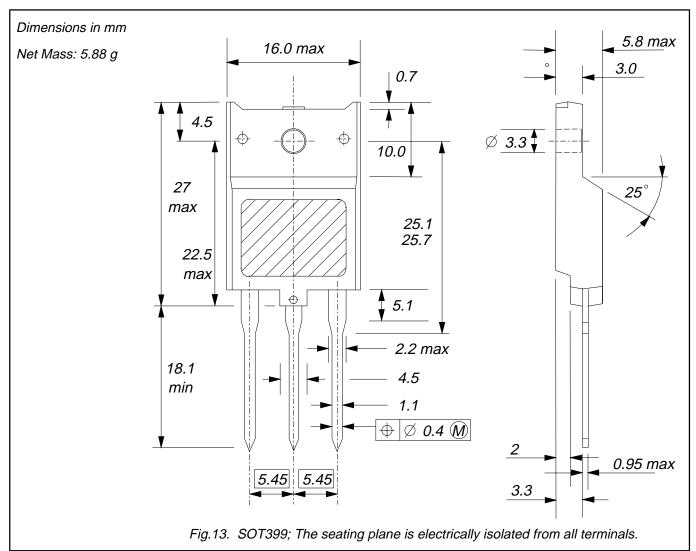


Fig.12. Forward bias safe operating area. $T_{hs} = 25^{\circ}C$ I Region of permissible DC operation. II Extension for repetitive pulse operation.

NB: Mounted without heatsink compound and 30 ± 5 newton force on the centre of the envelope.

BU508AX

MECHANICAL DATA



- Refer to mounting instructions for F-pack envelopes.
 Epoxy meets UL94 V0 at 1/8".

BU508AX

DEFINITIONS

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limitin arrealises				

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

© Philips Electronics N.V. 1997

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, it is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent or other industrial or intellectual property rights.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.